

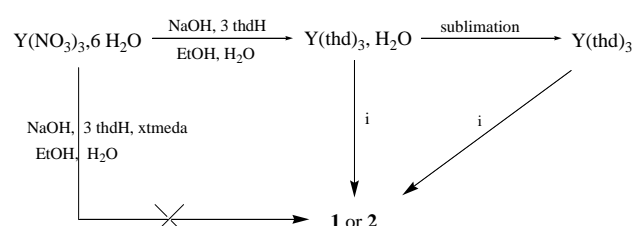
NEW YTTRIUM PRECURSORS FOR YBCO FILMS  
PREPARED BY PI-MOCVD

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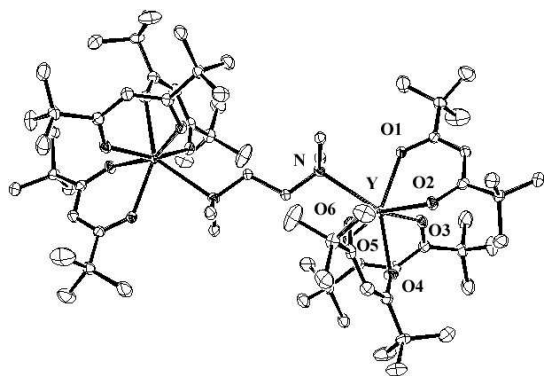
Metal  $\beta$ -diketonates  $M(\text{thd})_x$  ( $\text{thd} = 2,2,6,6$ -tetramethyl-3,5 heptanedionate) are commonly used as precursors for  $\text{YBa}_2\text{Cu}_3\text{O}_7$  (YBCO) films in MOCVD technologies. Yttrium and barium  $\beta$ -diketonates are moisture sensitive and need to be handled with cares. This instability is a limiting factor for the industrial production of YBCO by MOCVD, provoking irreproducibility. This problem can be alleviated by the use of Lewis bases saturating the metal coordination sphere [1,2].

$\text{Y}(\text{thd})_3(\text{TMEDA})$  (**1**) and  $[\text{Y}(\text{thd})_3]_2(\text{TMEDA})$  (**2**) compounds are prepared in high yields (80%) by mixing  $\text{Y}(\text{thd})_3(\text{H}_2\text{O})$  or  $\text{Y}(\text{thd})_3$  and  $\text{Me}_2\text{NC}_2\text{H}_4\text{NMe}_2$  (in appropriate stoichiometries) in hexane at room temperature (scheme 1). The one pot synthesis from  $\text{Y}(\text{NO}_3)_3 \cdot 6 \text{H}_2\text{O}$  is unsuccessful due to sodium contamination.



**Scheme 1** : Syntheses of compound **1** and **2**. conditions and reagents : *i*; hexane, *x* tmeda, 20°C.

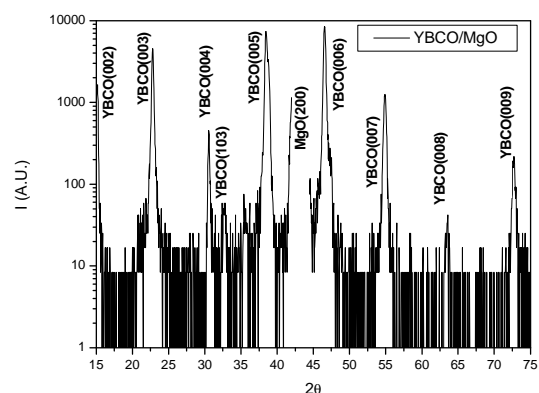
The formation of the species was examined by nuclear magnetic resonance and FT-IR spectroscopy. The structure of **2** was confirmed by single-crystal X-ray diffraction studies (figure 1). It is a dimer based on two  $\text{Y}(\text{thd})_3$  units linked by a tmeda ligand in an unusual bonding mode. The yttrium atom is seven-coordinated, with a distorted monocapped trigonal prismatic geometry.



**Figure 1** : Molecular structure of **2**

Their thermal behaviors were also characterized by TGA and sublimation experiments. Attempts to sublime **1-2** (140 °C under  $P=2.10^{-4}$  torr) result in dissociation of the Y-TMEDA bond and sublimation of  $\text{Y}(\text{thd})_3$ . Similar trends are observed on the DTA/TGA plots.

$\text{Y}(\text{thd})_3(\text{TMEDA})$  (**1**), due to its better solubility than **2**, was used to deposited YBCO films. We used the same deposition conditions that in previous works, for growth of YBCO films from  $\beta$ -diketonates [3]. YBCO films deposited on  $\text{LaAlO}_3$  and MgO were superconductor. XRD diagram corroborates the formation of the orthorhombic phase  $\text{YBa}_2\text{Cu}_3\text{O}_7$  (PDF 84-1760). From figure 2, presenting the XRD diagram obtained from YBCO film on MgO, all (00l) diffractions peaks are present, and only a very small signal from the (103) diffraction is detected. Films were in-plane and out-of-plane textured. The thickness of the grown films was 800 nm. Films grown on  $\text{LaAlO}_3$  presented a very sharp superconducting transition, with a  $T_c(\text{onset})$  of 91K and a  $\Delta T_c$  of 0.6K. The  $J_c$  value for this sample was 0.2  $\text{MA}/\text{cm}^2$ .



**Figure 2** : XRD diagram from YBCO film on MgO

For the first time, homometallic  $\text{Y}(\text{thd})_3$  (TMEDA) (**1**) and  $[\text{Y}(\text{thd})_3]_2(\text{TMEDA})$  (**2**) have been prepared and characterized. These precursors are stable in air. Depositions of  $\text{Y}_2\text{O}_3$  and YBCO has allowed to validate the use of  $\text{Y}(\text{thd})_3(\text{TMEDA})$  as precursor for PI MOCVD. In particular, deposition of YBCO from a single solution with  $\beta$ -diketonates for Ba and Cu was possible. These features seem very promising for the industrial fabrication of YBCO layers by MOCVD

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